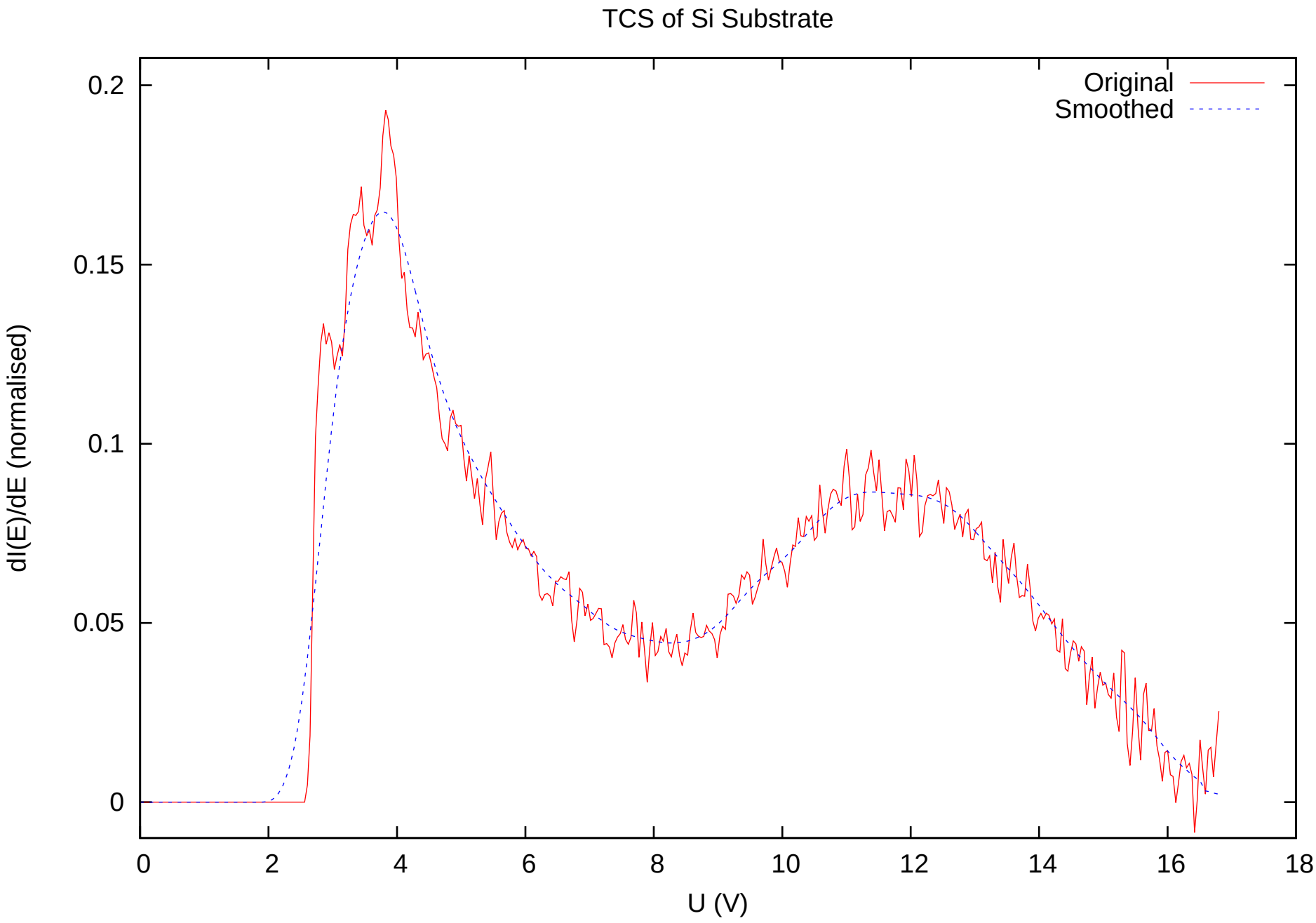
TCS of Si Substrate
Original
Smoothed
dI(E)/dE (normalised)
U (V)
0.2
0.15
0.1
0.05
0
0
2
4
6
8
10
12
14
16
18